PRODUCTION CHANGE SHEET FOR

PORTABLE RECEIVERS

MODEL 4ER28A1 & 11; REV. J

MODEL 4ER28A2 & 12; REV. P

MODEL 4ER28B1 & 11; REV. P

MODEL 4ER28B2 & 12; REV. R

Changes listed below are identified by the letter appearing in the REV. Pad. $\dot{}$

REV. A (Models 4ER28B1,2,11,12 only) - resistors changed to improve performance. Transistors changed to agree with changes in vendor designations.

Part Changed	Was	Changed To
Q303 thru Q305	Transistor, G-E Type 2N450.	Transistor, G-E Type 2N450 or 4JX1A810.
Q310	Transistor, G-E Type ZJ22.	Transistor, G-E Type 3N37.
G303,4-R1 and G303,4-R5	Resistor: composition, 6200 ohms ±5%, 1/10 w. G-E Part No. C-3R151-P622J.	Resistor: composition, 3900 ohms $\pm 10\%$, $1/10$ w. G-E Part No. C-3R151-P392K.
G303,4-R3 and G303,4-R7	Resistor: composition, 4700 ohms ±10%, 1/4 w. G-E Part No. C-3R152-P472K.	Resistor; composition, 2200 ohms ±10%, 1/4 w. G-E Part No. C-3R152-P222K.
G303,4-R4 G303,4-R8	Resistor: composition, 3900 ohms ±10%, 1/10 w. G-E Part No. C-3R151-P392K.	Resistor: composition, 2200 ohms ±10%, 1/10 w. G-E Part No. C-3R151-P222K.
G303,4-Q1	Transistor, G-E Type 4JX3B502.	Transistor, G-E Type 4JX3B512.
Z304-Q1	Transistor, G-E Type 4JD3B5.	Transistor, G-E Type 4JD3B5 or 4JX3B505.
Z304-Q2	Transistor, G-E Type 4JD2A32.	Transistor, G-E Type 4JD2A24.

Changed delineation of parts as follows:

Changed To:
Q303, 2N450/4JX1A810
Q304, 2N450/4JX1A810
Q305, 2N450/4JX1A810
Q310, 3N37
G303-R1, 3900, 1/10 w.
G303-R3, 2200, 1/4 w.
G303-R4, 2200, 1/10 w.
G303,4-R5, 3.9K
G303,4-R7, 2.2K
G303,4-R8, 2.2K
G303-Q1, 2JX3B512
Z304-Q1, 4JD3B5/4JX3B505
Z304-Q2, 4JD2A24

REV. B (Models 4ER28B1,2,11,12 only) - resistors changed to improve sensitivity.

Part Changed	Was	Changed To
Z303-R11 and Z303-R16	Resistor: composition, 3300 ohms $\pm 10\%$, $1/4$ w. G-E Part No. C-3R152-P332K.	Resistor: composition, 2200 ohms ±10%, 1/4 w. G-E Part No. C-3R152-P222K.

Elementary Diagram Changes

Changed delineation of parts as follows:

Z303-R11, 3.3K to Z303-R11, 2.2K Z303-R16, 3.3K to Z303-R16, 2.2K

REV.	C	(Models	4ER28B1,2,11,1	12 only)	_	decreases	collector	current
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Part Changed	Was	Changed To
G303-R1	Resistor: composition, 3900 ohms ±10%, 1/10 w. G-E Part No. C-3R151-P392K.	
G303-R3	Resistor: composition, 2200 ohms $\pm 10\%$, $1/4$ w. G-E Part No. C-3R151-P222K.	
G304-R1,R5	Resistor: composition, 3900 ohms ±10%, 1/10 w. G-E Part No. C-3R151-P392K.	Resistor: composition, 2200 ohms $\pm 10\%$, $1/4$ w. G-E Part No. C-3R151-P222K.
G304-R3,R7	Resistor: composition, 2200 ohms $\pm 10\%$, $1/4$ w. G-E Part No. C-3R151-P222K.	3900 ohms $\pm 10\%$,
Elementary Dia	agram Changes	

G303-R1, 3.9K to G303-R1, 2.2K G303-R3, 2.2K to G303-R3, 3.9K G304-R1, 3.9K to G304-R1, 2.2K G304-R3, 2.2K to G304-R3, 3.9K G304-R5, 3.9K to G304-R5, 2.2K G304-R7, 2.2K to G304-R7, 3.9K

REV. D (Models 4ER28B1,2,11,12 only) - improve first and second image ratio. Increase audio high frequency response. Reduce standby current drain.

Part Changed	<u> Was</u>	Changed To
RT301	Thermistor: 10 ohms Thermistor: 30 of ±10%, max input watts 1.0 at 40°C, temp coefficient 1400 ±10%. Similar to Globar Type 781F. G-E Dwg. No.	
	B-5490828-P1.	B-5490828-P2.
R330	Resistor: composition, 750 ohms ±5%, 1/2 w. G-E Part No. C-3R77-P751J.	Resistor: composition, 2700 ohms $\pm 10\%$, $1/2$ w. G-E Part No. C-3R77-P272K.

Part Changed	Was	Changed To
C326	Capacitor: Mylar, dielectric; 0.22 mfd ±20%, 100 v d-c w. Similar to Goodall Electric Co. Type 663-UW. G-E Dwg. No. B-7491930-P110.	Deleted.

Addition Changes

Removed ground link from Z304 nearest "cold" end of Cl. Added shield can to solder side of RF board under first mixer and multiplier.

Elementary Diagram Changes

Deleted C326, 0.22 MFD Changed delineation of parts as follows:

RT301, 10 to RT301, 30. R330, 75 to R330, 2.7K

Outline Diagram Changes

Deleted C326 and deleted ground link from Z304.

REV. E (Models 4ER28B1,2,11,12 only) - improves limiter action and reduces audio distortion at high modulation levels.

Part Changed	Was	Changed To
Z302-C8	Capacitor: ceramic Hi-K disk, insula- ted; 0.025 MFD +80% -20%, 50 v d-c w. Sprague Cat. #29C187. G-E Dwg. No. B-7491827-P3.	Capacitor: Mylar dielectric; 0.01 mfd ±20%, 50 v d-c w. Similar to Goodall Type 601PE. G-E Dwg. No. B-5491189-P105.
Z302-C9 Z303-C4 Z303-C7 Z303-C10 Z303-C13 Z303-C14	Capacitor: ceramic Hi-K disk, insulat- ed; 0.1 mfd ±80% -30%, 50 v d-c w. Sprague Cat. #36C172. G-E Dwg. No. B-7491827-P5.	mfd $\pm 20\%$, 100 v d-c w. Similar to

Changed delineation of parts as follows:

Z302-C8, .025 MFD to Z302-C8,.068 MFD Z302-C9, . 1 MFD to Z302-C9, .022 MFD . 1 Z303-C4, MFD to Z303-C4, .022 MFD Z303-C7, . 1 MFD to Z303-C7, .022 MFD Z303-C10, .1 MFD to Z303-C10, .022 MFD Z303-C13, .1 Z303-C14, .1 MFD to Z303-C13, .022 MFD $\,$ MFD to Z303-C14, .022 MFD

REV. A (Models 4ER28A1,2,11,12 only) REV. F (Models 4ER28B1,2,11,12 only)

Purpose of change - to improve audio response and distortion.

Part Changed	Was	Changed To
R323	Resistor: composition, 5600 ohms $\pm 10\%$, $1/4$ w. G-E Part No. C-3R152-P562K.	Resistor: composition, 4700 ohms ±10%, 1/4 w. G-E Part No. C-3R152-P472K.

Elementary Diagram Changes

R323, 5.6K was changed to R323, 4.7K.

REV. B (Models 4ER28A1,11 only) REV. G (Models 4ER28B1,11 only)

Purpose of change - to enable oscillation to tune over 144-150 Mc frequency range.

Capacitor: ceramic Deleted disc; insulated, temp compensating; 15 mmfd ±5%, 500 v d-c w, -80 temp coef. G-E Dwg. No. C-7774846-P244.	Part Changed	Was	Changed To
	C361	disc; insulated, temp compensating; 15 mmfd ±5%, 500 v d-c w, -80 temp coef. G-E Dwg. No.	Deleted

C374 Added Capacitor: ceramic disc; insulated, temp compensating; 27 mmfd ±5%, 500 v d-c w, -80 temp coef. G-E Dwg. No. C-7774846-P249.

REV. C (Models 4ER28A1,2,11,12 only)

REV. H (Models 4ER28B1,2,11,12 only)

Purpose of change - to facilitate the procurement of a maximum number of transistors.

Part Changed	Was	Changed To		
Q309	Transistor, G-E Type 3N37.	Transistor, G-E Type 3N37 or 4JX3C508.		
Q310 and Q311	Transistor, G-E Type 3N37/4JX3C507/ 4JX3C509.	Transistor, G-E Type 3N37 or 4JX3C507.		

Elementary Diagram Changes

Changed delineation of parts as follows:

<u>Was</u> :	Changed To:	
Q309, 3N37	Q309,	3N37/4JX3C508
Q310, 3N37/4JX3C507/4JX3C509	Q310,	3N37/4JX3C507
Q311, 3N37/4JX3C507/4JX3C509	Q3 [:] 11,	3N37/4JX3C507

REV. D (Models 4ER28A1,2,11,12 only) REV. J (Models 4ER28B1,2,11,12 only)

Purpose of change - to optimize design in consideration of component variations.

Part Changed	Was	Changed To
R323	Resistor: composition, 4700 ohms ±10%, 1/4 w. G-E Dwg. No. C-3R152-P472K.	Resistor: composition, 5100 ohms ±10%, 1/4 w. G-E Dwg. No. C-3R152-P512J.

REV. E (Models 4ER28A1,2,11,12 only) REV. K (Models 4ER28B1,2,11,12 only)

To stabilize discriminator idling for varying input signal levels.

Part Changed	Was	Changed To
Z303-Q4 and Z303-Q5	Transistor, G-E Type 2N450/4JX1A552.	Transistor, G-E Type 2N188A.

Changed reference to Z303-Q4 and Z303-Q5 from 2N450/4JX1A552 to 2N188A.

REV. F (Models 4ER28A2, Al2 only) REV. L (Models 4ER28B2, Bl2 only)

Purpose of change - to insure tuning overlap at lower end of band.

Part Changed

Was

Changed To

C360

Capacitor: ceramic disk, insulated, temp compensating 7 mmf ±0.25 mmfd, 500 VDCW -80 temp coef. G-E Dwg. No. C-7774846-P238.

Capacitor: ceramic disk insulated, temp compensating 9 mmf, ±5%, 500 VDCW -80 temp. coef. G-E Dwg. No. C-5496218-P239.

REV. F (Models 4ER28A1,11 only)

REV. G (Models 4ER28A2,12 only)

REV. L (Models 4ER28B1,11 only)

REV. M (Models 4ER28B2,12 only)

Purpose of change - To increase oscillator activity.

All models

Part Changed

Was

Changed To

G303/304 C8

Added

Capacitor: fixed ceramic disc, insulated, temp. compensating. Capacity 10 mmf., ±10%, 500 vdcw G-E Dwg. No. C-5496218-P10.

Models 4ER28All, 12, 4ER28Bll, 12 only -

Part Changed

Was

Changed To

G304 C9

Added

Capacitor: fixed ceramic disc, insulated, temp. compensating. Capacity 10 mmf., ±10%, 500 vđcw. G-E Dwg. No. C-5496218-P10.

Add C8 to G303 and G304 between emitter and base 2 of Q1. C9 to G304 between emitter and base of Q2.

- REV. G (Models 4ER28A1,11 only)
- REV. H (Models 4ER28A2,12 only)
- REV. M (Models 4ER28B1,11 only)
- REV. N (Models 4ER28B2,12 only)

Purpose of change - To increase receiver R.F. sensitivity.

Part Changed

Was

Changed To

Z304-C3 and Z304-C6

Capacitor: fixed, moulded, 0.47 pf ± 0.047 pf, 500 vdcw, 0 temp coef. Jeffers Mfg. Co. Type JM-5/32. G-E Dwg. No. K-7130348-P15. K-7130348-P1.

Capacitor: fixed, moulded, $0.62 \text{ pf } \pm 5\%$, 500 vdcw0 temp coef. Jeffers Mfg. Co. Type JM-5/32. G-E Dwg. No.

Elementary Diagram Changes

Change values of Z304-C3 and Z304-C6.

- REV. H (Models 4ER28A1,11 only)
- REV. J (Models 4ER28A2,12 only)
- REV. N (Models 4ER28B1,11 only)
- REV. P (Models 4ER28B2,12 only)

Purpose of change - To assure the use of high quality transistor.

Change - New G.E. part numbers have been assigned to transistors Q303, Q304, Q305, Q306, Q307, Q308, Q309, Z303 -Q4 and Q5, and Z304 -Q1 and Q2.

- REV. J (Models 4ER28A1,11 only)
- REV. K (Models 4ER28A2,12 only)
- REV. P (Models 4ER28B1,11 only)
- REV. R (Models 4ER28B2,12 only)

Purpose of change - To improve operation of receivers at high humidity.

Change - The moisture resisting treatment of the coils in the 290 kc filter has been improved.

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